

808nm 2W Semiconductor Laser datasheet

P/N :WPFT-02A

Features:

808nm Central wavelength

Output power 2W

Multimode fiber



Applications

Sensing

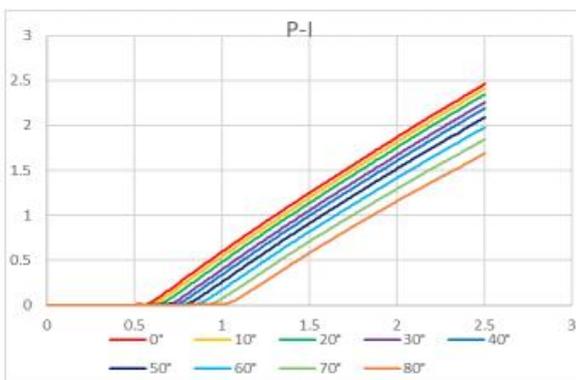
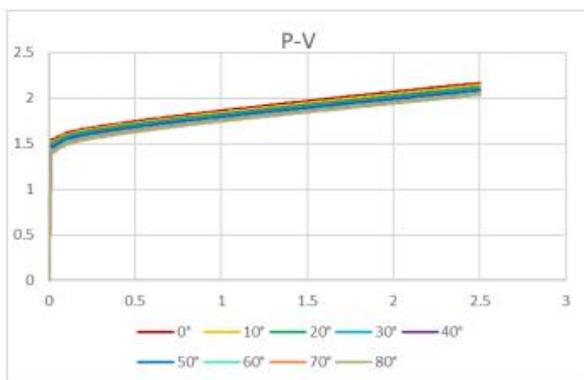
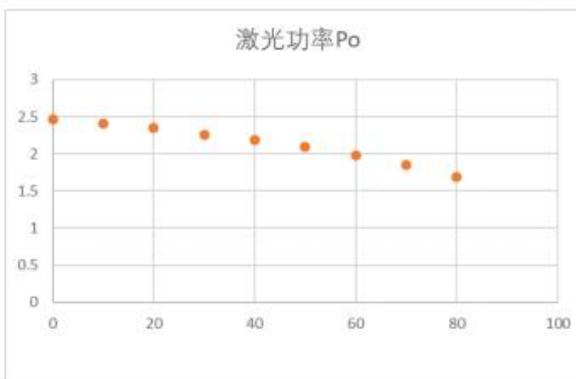
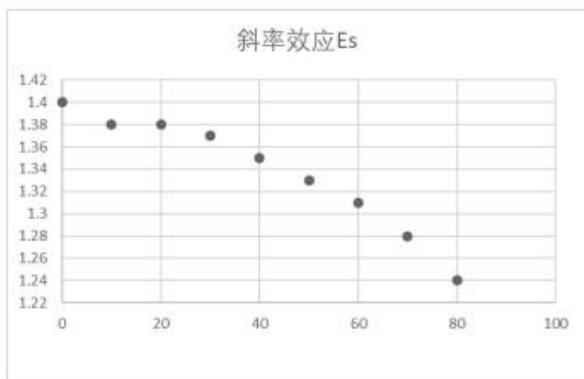
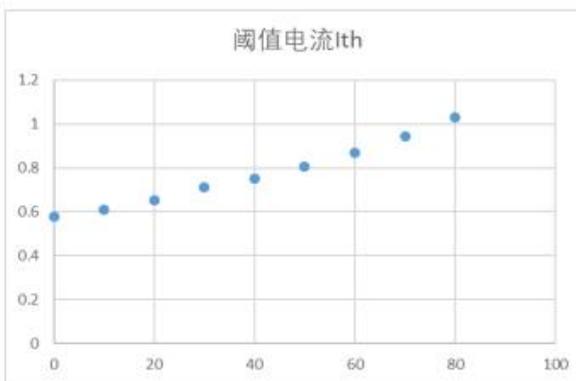
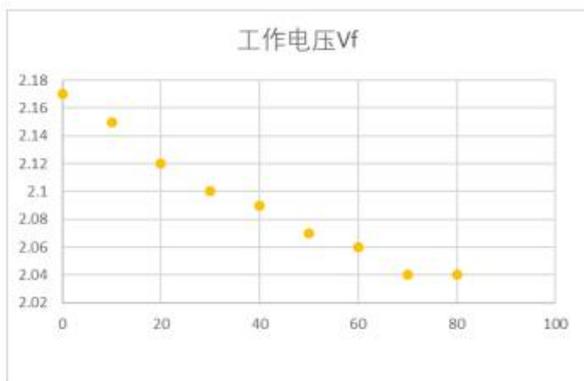
Communication equipment

Scientific Research

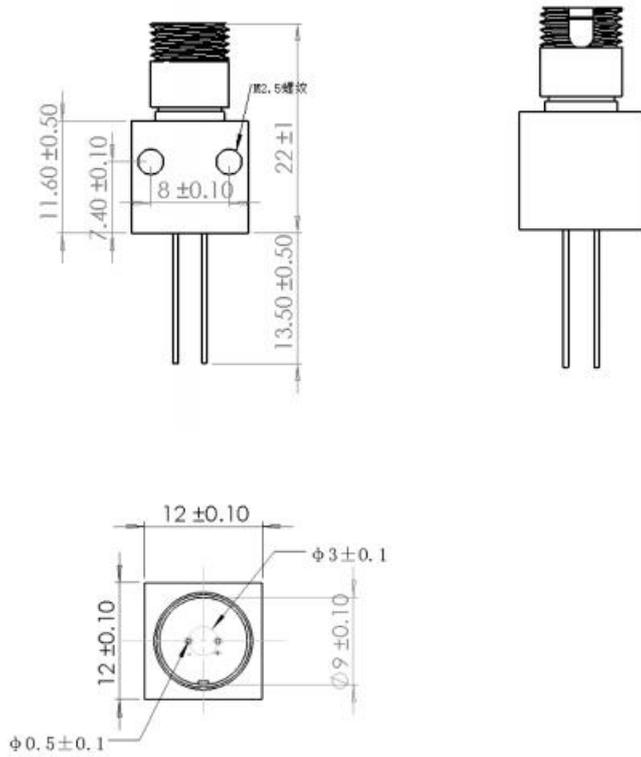
Electrical/Optical Characteristics (T _{sub} =25°C)		Symbol	Units	Value		
				Min	Typ.	Max
Optical Parameters	Output Power (CW)	P ₀	W	1.9	2	-
	Center Wavelength	λ	nm	808±10		
	Spectral Width (FWHM)	$\Delta\lambda$	nm	-	3	-
	Temperature Drift Coefficient	$\Delta\lambda/\Delta T$	nm/°C	-	0.3	-
Electrical parameters	Threshold current	I _{th}	A	-	0.65	-
	Conversion Efficiency	η	-	-	35%	-
	Operating Current	I _{op}	A	-	2.5	-
	Operating Voltage	V _{op}	V	-	2.2	-
Fiber Optic Parameters	Core Diameter	D _{core}	μm	-	105	-
	Cladding Diameter	D _{clad}	μm	-	125	-
	Coating Diameter	D _{buf}	μm	-	250	-
	Numerical Aperture	N.A.	-	-	0.22	-
	Connector	-	-	-	FC	-
	Operating Temperature	T _{op}	°C	10		30

Other parameters	Storage Temperature	Tat	°C	-20	-	70
	Mean Time To Failure	MTTF	h	-	10000	-
	Soldering Temperature	T sold	°C	-	-	260
	Soldering Time	t	sec	-	-	10
	Size		mm	-	12*12*22	-

Temperature characteristic:



Outline Drawings(mm):



Cautions:

1. Avoid direct laser beam exposure to eyes and skin while the laser is operating.
2. Electrostatic discharge (ESD) protection measures must be taken during transportation, storage, and use. Short-circuit protection is required between pins during transportation and storage.
3. Use soldering method to connect leads, keeping solder joints as close to the pin roots as possible. Maintain soldering temperature below 260°C and duration less than 10 seconds.
4. Operate within rated current and voltage specifications.
5. Use constant current power supply and avoid surge currents during operation.
6. Ensure proper heat dissipation while the laser is operating, maintaining case temperature between 10°C and 30°C.

